

		Sun.	Mon.	Tues.		Wed.		Thurs.
@		Auditorium Descartes	Auditorium Ronsard	Auditorium Ronsard	Auditorium Descartes	Auditorium Ronsard	Auditorium Descartes	Auditorium Ronsard
08:30		Welcome Coffee & Opening	Opening	Tu-1A Diodes & Superjunctions	Tu-1B : MOS Processing	We-1A : Advanced Processing	We-1B : MOS Interface	Th-1A : Harsh Environment, Ics & Sensors
10:00		Su-1A : Tutorial	Plenary session	Coffee Break	Coffee Break	Coffee Break	Coffee Break	Coffee Break
			Coffee Break					
12:00		Mo-1A : SiC Epitaxy	Tu-2A : Extended defects	Tu-2B : Materials & Defects	We-2A : Bulk growth	We-2B : Characterization techniques	Th-2A : Harsh Environment, Ics & Sensors	
13:30		LUNCH BREAK	LUNCH BREAK	LUNCH Break	LUNCH Break	LUNCH Break	LUNCH Break	LUNCH BREAK
		Su-2A : Tutorial	Mo-2A : MOSFETs	Tu-3A : 3C-SiC	Tu-3B : Schottky contacts	We-3A : Point defects	We-3B : Implantation and annealing	End of the conference at 14:00
	Coffee Break		Coffee Break	Coffee Break	Coffee Break	Coffee Break		
	Mo-3A : Quantum Technology		Tu-4A : HV and advanced devices	Tu-4B : Fundamental properties	We-4A : New material aspects	We-4B : Devices & Reliability		
17:00		BREAK / Badges	INVITED POSTER introduction					
18:30		WELCOME PARTY (from 18:30 @ 2nd Floor)	INDUSTRIAL SESSION @ - 2nd Floor	Tu-P : POSTER SESSION		We-P : POSTER SESSION		
19:30							GALA DINNER at "La Grange de Meslay" (from 19:30)	
			INDUSTRIAL Exhibition 08:00/19:45 @ - 2nd Floor	INDUSTRIAL Exhibition 08:00/19:00 @ - 2nd Floor		INDUSTRIAL Exhibition 08:00/19:00 @ - 2nd Floor		INDUSTRIAL Exhibition 08:30/14:00 @ -2 nd Floor